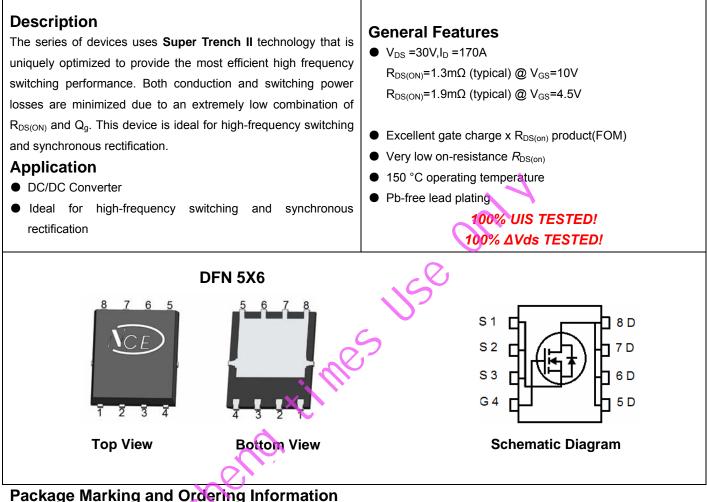


NCE N-Channel Super Trench II Power MOSFET



Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
P015N30GU	NCEP015N30GU	DFN5X6-8L	-	-	-

Absolute Maximum Ratings (Tc=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	Vds	30	V	
Gate-Source Voltage	Vgs	±20	V	
Drain Current-Continuous	Ι _D	170	А	
Drain Current-Continuous(T _C =100 ℃)	I _D (100℃)	130	A	
Pulsed Drain Current	I _{DM}	680	A	
Maximum Power Dissipation	PD	95	W	
Derating factor		0.76	W/°C	
Single pulse avalanche energy (Note 5)	E _{AS}	583	mJ	
Operating Junction and Storage Temperature Range	T _J ,T _{STG}	-55 To 150	°C	

Thermal Characteristic

Thermal Resistance, Junction-to-Case ^(Note 2)	$R_{ extsf{ heta}JC}$	1.31	°C/W
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NCEP015N30GU

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250µA	30		-	V
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =30V, V_{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V_{GS} =±20V, V_{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	1.0	1.6	2.0	V
Drain-Source On-State Resistance	Б	V_{GS} =10V, I _D =85A	-	1.3	1.5	mΩ
	R _{DS(ON)}	V_{GS} =4.5V, I _D =85A	-	1.9	2.3	mΩ
Forward Transconductance	g fs	V_{DS} =5V,I _D =85A	65	-	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C _{lss}		-	2988.1	-	PF
Output Capacitance	C _{oss}	V _{DS} =15V,V _{GS} =0V F=1.0MHz	-	1407.8	-	PF
Reverse Transfer Capacitance	C _{rss}		-	100.8	-	PF
Switching Characteristics (Note 4)		15				
Turn-on Delay Time	t _{d(on)}	V ²	-	5.5	-	nS
Turn-on Rise Time	tr	V _{DD} =15V,I _D =85A	-	7.5	-	nS
Turn-Off Delay Time	$t_{d(off)}$	V _{GS} =10V,R _G =1.6Ω	-	33.0	-	nS
Turn-Off Fall Time	t _f		-	5.0	-	nS
Total Gate Charge	Qg	V _{DS} =15V,I _D =85A,	-	46.1	-	nC
Gate-Source Charge	Q_{gs} $V_{DS}=15V, ID=65A,$ Q_{gd} $V_{GS}=10V$		-	5.7		nC
Gate-Drain Charge		-	9.2		nC	
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V _{SD}	V_{GS} =0V,I _S =85A	-		1.2	V
Diode Forward Current (Note 2)	I _S		-	-	170	А
Reverse Recovery Time	t _{rr}	T_J = 25°C, I_F = I_S	-	16	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs ^(Note3)	-	28	-	nC



1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. Surface Mounted on FR4 Board, t \leq 10 sec.

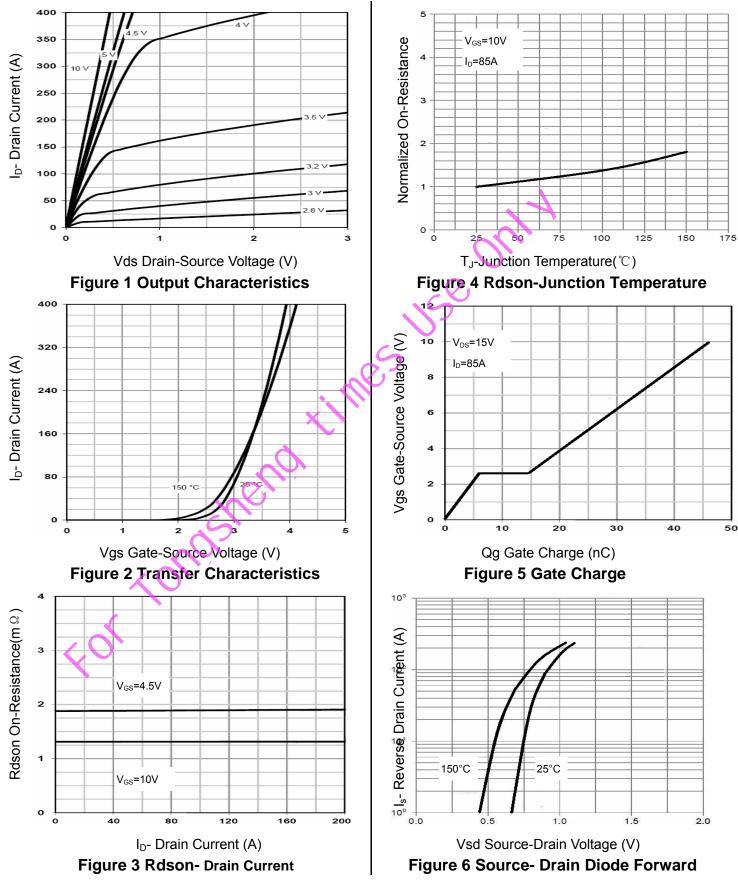
3. Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.

4. Guaranteed by design, not subject to production

5. EAS condition : Tj=25 $^\circ \! \mathrm{C}$,V_DD=20V,V_G=10V,L=0.5mH,Rg=25 Ω

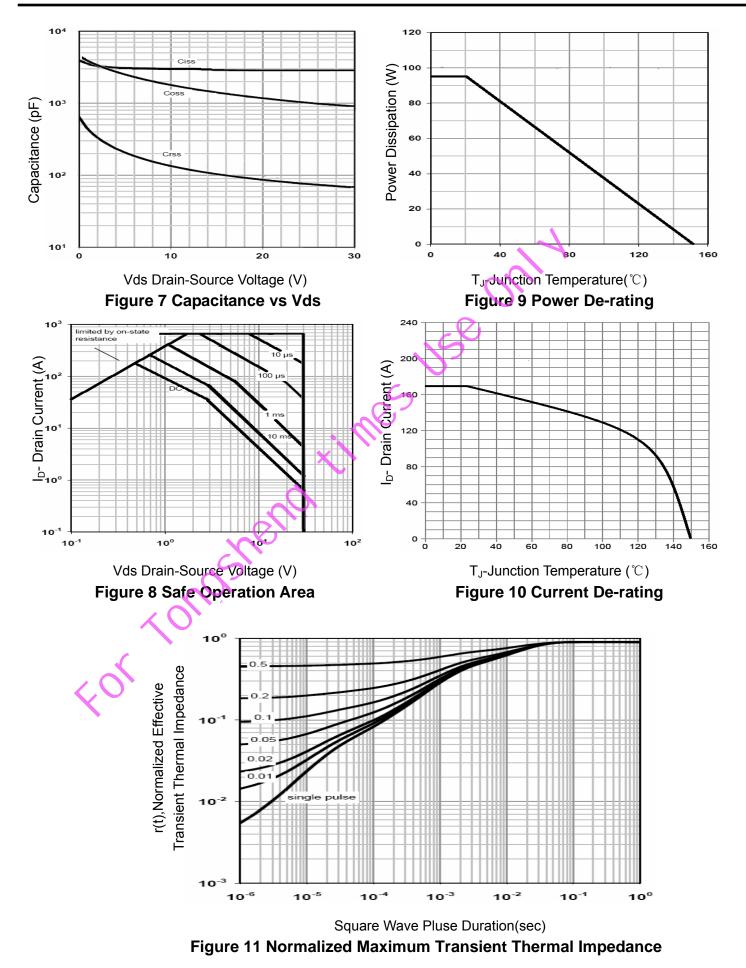


Typical Electrical and Thermal Characteristics





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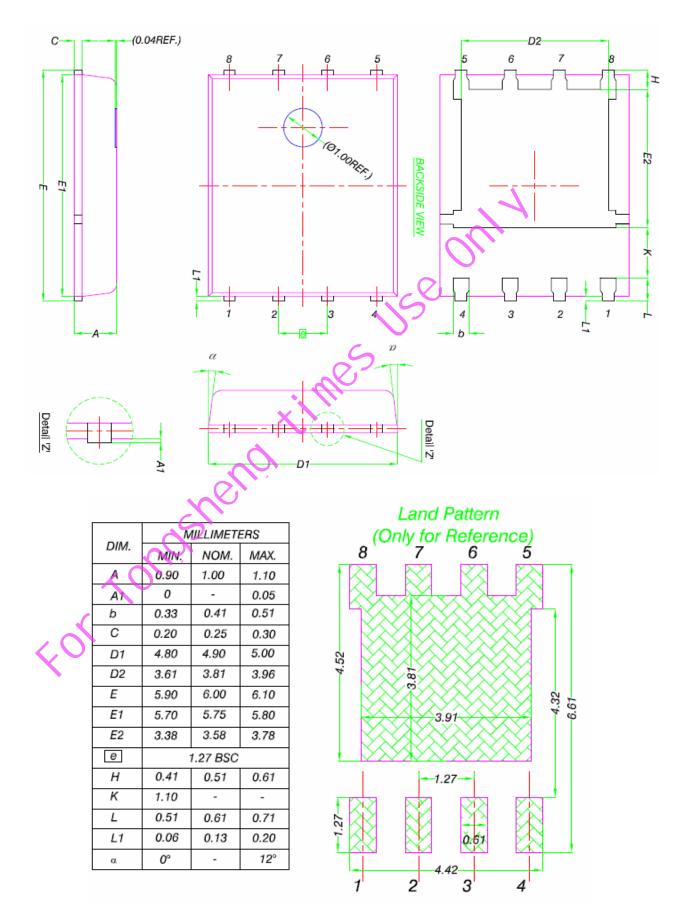


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DFN5X6-8L Package Information





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